

# Up to 6 GHz Low Noise Silicon Bipolar Transistor

## Technical Data

#### AT-41470

### **Features**

- Low Noise Figure: 1.6 dB Typical at 2.0 GHz 3.0 dB Typical at 4.0 GHz
- **High Associated Gain:** 14.5 dB Typical at 2.0 GHz 10.5 dB Typical at 4.0 GHz
- High Gain-Bandwidth Product: 8.0 GHz Typical f<sub>T</sub>
- Hermetic, Gold-ceramic Microstrip Package

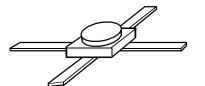
#### **Description**

Hewlett-Packard's AT-41470 is a general purpose NPN bipolar transistor that offers excellent high frequency performance. The AT-41470 is housed in a hermetic, high reliability gold-ceramic 70 mil microstrip package. The 4 micron emitter-to-emitter pitch enables this transistor to be used in many different functions. The 14 emitter

finger interdigitated geometry yields an intermediate sized transistor with impedances that are easy to match for low noise and moderate power applications. This device is designed for use in low noise, wideband amplifier, mixer and oscillator applications in the VHF, UHF, and microwave frequencies. An optimum noise match near  $50~\Omega$  at  $1~\mathrm{GHz}$ , makes this device easy to use as a low noise amplifier.

The AT-41470 bipolar transistor is fabricated using Hewlett-Packard's 10 GHz  $f_T$  Self-Aligned-Transistor (SAT) process. The die is nitride passivated for surface protection. Excellent device uniformity, performance and reliability are produced by the use of ionimplantation, self-alignment techniques, and gold metalization in the fabrication of this device.

70 mil Package



4-119 5965-8927E

**AT-41470 Absolute Maximum Ratings** 

| Symbol             | Parameter                 | Units | Absolute<br>Maximum <sup>[1]</sup> |
|--------------------|---------------------------|-------|------------------------------------|
| $V_{\mathrm{EBO}}$ | Emitter-Base Voltage      | V     | 1.5                                |
| $V_{CBO}$          | Collector-Base Voltage    | V     | 20                                 |
| $V_{CEO}$          | Collector-Emitter Voltage | V     | 12                                 |
| $I_{\mathrm{C}}$   | Collector Current         | mA    | 60                                 |
| $P_{T}$            | Power Dissipation [2,3]   | mW    | 500                                |
| $T_{\rm j}$        | Junction Temperature      | °C    | 200                                |
| $T_{STG}$          | Storage Temperature       | °C    | -65 to 200                         |

| Thermal Resistance $[2,4]$ : |  |
|------------------------------|--|
| $\theta_{\rm jc} = 175$ °C/W |  |

#### **Notes:**

- 1. Permanent damage may occur if any of these limits are exceeded.
- 2.  $T_{CASE} = 25$ °C.
- 3. Derate at 5.7 mW/°C for  $T_{\rm C} > 113$  °C.
- 4. The small spot size of this technique results in a higher, though more accurate determination of  $\theta_{jc}$  than do alternate methods. See MEASUREMENTS section "Thermal Resistance" for more information.

## Electrical Specifications, $T_A = 25^{\circ}C$

| Symbol                    | <b>Parameters and Test Conditions</b>   |  | Units | Min. | Тур.                 | Max. |
|---------------------------|---|--|-------|------|----------------------|------|
| $ S_{21E} ^2$             | Insertion Power Gain; $V_{CE} = 8 \text{ V}$ , $I_{C} = 25 \text{ mA}$        | $f = 2.0 \mathrm{GHz}$<br>$f = 4.0 \mathrm{GHz}$   | dB    |      | 12.0<br>6.5          |      |
| P <sub>1 dB</sub>         | Power Output @ 1 dB Gain Compression $V_{CE} = 8V, I_C = 25mA$                | $f = 2.0 \mathrm{GHz}$<br>$f = 4.0 \mathrm{GHz}$   | dBm   |      | 19.0<br>18.5         |      |
| $G_{1 dB}$                | 1 dB Compressed Gain; $V_{CE} = 8 \text{ V}, I_{C} = 25 \text{ mA}$           | $f = 2.0 \mathrm{GHz}$<br>$f = 4.0 \mathrm{GHz}$   | dB    |      | 15.0<br>10.5         |      |
| NF <sub>O</sub>           | Optimum Noise Figure: $V_{CE} = 8 \text{ V}, I_{C} = 10 \text{ mA}$           | f = 1.0 GHz<br>f = 2.0 GHz<br>f = 4.0 GHz  | dB    |      | 1.3<br>1.6<br>3.0    | 1.9  |
| $G_{A}$                   | Gain @ NF <sub>O</sub> ; $V_{CE} = 8 \text{ V}$ , $I_{C} = 10 \text{ mA}$     | $\begin{aligned} &f=1.0\mathrm{GHz}\\ &f=2.0\mathrm{GHz}\\ &f=4.0\mathrm{GHz} \end{aligned}$ | dB    | 13.0 | 18.5<br>14.5<br>10.5 |      |
| $\mathbf{f}_{\mathrm{T}}$ | Gain Bandwidth Product: $V_{CE} = 8 \text{ V}, I_{C} = 25 \text{ mA}$         |  | GHz   |      | 8.0                  |      |
| h <sub>FE</sub>           | Forward Current Transfer Ratio; $V_{CE} = 8 \text{ V}, I_{C} = 10 \text{ mA}$ |  | _     | 30   | 150                  | 300  |
| $I_{CBO}$                 | Collector Cutoff Current; $V_{CB} = 8 \text{ V}$                              |  | μA    |      |                      | 0.2  |
| $I_{\mathrm{EBO}}$        | Emitter Cutoff Current; $V_{EB} = 1 V$  |  | μΑ    |      |                      | 1.0  |
| $C_{CB}$                  | Collector Base Capacitance <sup>[1]</sup> : $V_{CB} = 8 V$ , $f = 1 MHz$      |  | pF    |      | 0.2                  |      |

## Note:

1. For this test, the emitter is grounded.

## AT-41470 Typical Performance, $T_A = 25$ °C

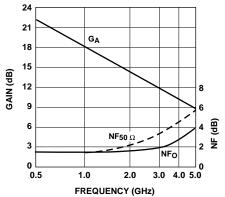


Figure 1. Noise Figure and Associated Gain vs. Frequency.  $V_{CE}=8\ V,\ I_{C}=10mA.$ 

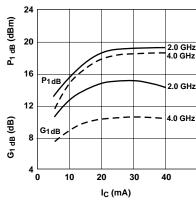


Figure 2. Output Power and 1 dB Compressed Gain vs. Collector Current and Frequency.  $V_{\rm CE}$  = 8 V.

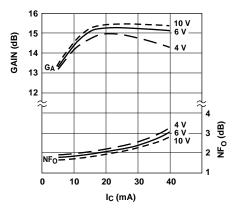


Figure 3. Optimum Noise Figure and Associated Gain vs. Collector Current and Collector Voltage.  $f=2.0\ GHz$ .

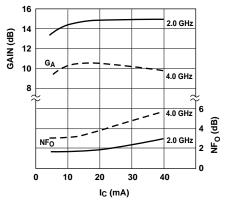


Figure 4. Optimum Noise Figure and Associated Gain vs. Collector Current and Frequency.  $V_{CE}$  = 8 V.

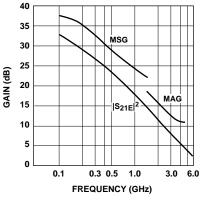


Figure 5. Insertion Power Gain, Maximum Available Gain and Maximum Stable Gain vs. Frequency. V<sub>CE</sub> = 8 V, I<sub>C</sub> = 25 mA.

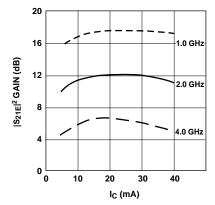


Figure 6. Insertion Power Gain vs. Collector Current and Frequency. V<sub>CE</sub> = 8 V.

AT-41470 Typical Scattering Parameters, Common Emitter,  $\rm Z_O=50~\Omega, T_A=25^{\circ}C, V_{CE}=8~V, I_C=10~mA$ 

| Freq. |      | $\overline{\mathbf{S}_{11}}$ |      | $\mathbf{S}_{21}$ |            |       | $\mathbf{S}_{12}$ |      | S    | 22   |
|-------|------|------------------------------|------|-------------------|------------|-------|-------------------|------|------|------|
| GHz   | Mag. | Ang.                         | dB   | Mag.              | Ang.       | dB    | Mag.              | Ang. | Mag. | Ang. |
| 0.1   | .79  | -37                          | 28.4 | 26.27             | 157        | -39.2 | .011              | 57   | .94  | -13  |
| 0.5   | .65  | -120                         | 22.3 | 13.05             | 110        | -30.8 | .029              | 40   | .62  | -30  |
| 1.0   | .61  | -155                         | 17.1 | 7.17              | 88         | -28.9 | .036              | 41   | .52  | -32  |
| 1.5   | .60  | -172                         | 13.9 | 4.93              | 76         | -27.5 | .042              | 46   | .50  | -36  |
| 2.0   | .60  | 176                          | 11.5 | 3.75              | 65         | -26.4 | .048              | 46   | .50  | -40  |
| 2.5   | .61  | 169                          | 9.7  | 3.06              | 59         | -26.0 | .050              | 58   | .48  | -41  |
| 3.0   | .62  | 161                          | 8.3  | 2.59              | 51         | -24.7 | .058              | 61   | .49  | -48  |
| 3.5   | .61  | 154                          | 7.0  | 2.24              | 42         | -23.2 | .069              | 63   | .51  | -56  |
| 4.0   | .60  | 146                          | 5.9  | 1.97              | 32         | -21.4 | .085              | 62   | .52  | -63  |
| 4.5   | .60  | 137                          | 4.9  | 1.77              | 24         | -20.1 | .099              | 59   | .55  | -69  |
| 5.0   | .60  | 127                          | 4.1  | 1.61              | 15         | -19.5 | .106              | 59   | .57  | -75  |
| 5.5   | .61  | 115                          | 3.4  | 1.47              | 6          | -18.3 | .121              | 56   | .58  | -80  |
| 6.0   | .64  | 104                          | 2.6  | 1.34              | <b>-</b> 4 | -17.4 | .135              | 53   | .57  | -87  |

AT-41470 Typical Scattering Parameters, Common Emitter,  $Z_O=50~\Omega, T_A=25^{\circ}C, V_{CE}=8~V, I_C=25~mA$ 

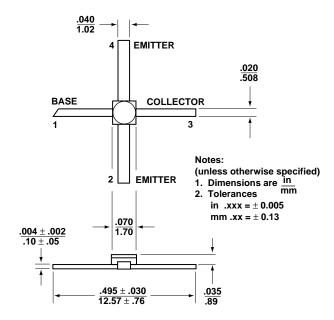
| Freq. |      | $\overline{\mathbf{S}_{11}}$ |      | $\mathbf{S}_{21}$ |      |       | $\mathbf{S}_{12}$ |      | S    | 22          |
|-------|------|------------------------------|------|-------------------|------|-------|-------------------|------|------|-------------|
| GHz   | Mag. | Ang.                         | dB   | Mag.              | Ang. | dB    | Mag.              | Ang. | Mag. | Ang.        |
| 0.1   | .64  | -62                          | 32.5 | 42.11             | 147  | -40.9 | .009              | 75   | .85  | -19         |
| 0.5   | .61  | -146                         | 23.7 | 15.31             | 100  | -34.4 | .019              | 47   | .50  | -30         |
| 1.0   | .61  | -170                         | 18.1 | 8.00              | 83   | -30.2 | .031              | 53   | .44  | -31         |
| 1.5   | .60  | 177                          | 14.7 | 5.42              | 72   | -29.1 | .035              | 62   | .44  | -34         |
| 2.0   | .61  | 167                          | 12.3 | 4.10              | 62   | -27.1 | .044              | 60   | .44  | -39         |
| 2.5   | .61  | 163                          | 10.4 | 3.32              | 58   | -25.7 | .052              | 67   | .43  | -39         |
| 3.0   | .62  | 156                          | 9.0  | 2.81              | 50   | -23.6 | .066              | 67   | .44  | -46         |
| 3.5   | .62  | 150                          | 7.7  | 2.44              | 41   | -22.6 | .074              | 67   | .46  | -55         |
| 4.0   | .62  | 142                          | 6.6  | 2.13              | 32   | -21.7 | .082              | 63   | .48  | -62         |
| 4.5   | .61  | 134                          | 5.6  | 1.91              | 24   | -20.1 | .099              | 62   | .50  | -68         |
| 5.0   | .60  | 123                          | 4.8  | 1.73              | 15   | -18.9 | .113              | 59   | .52  | -73         |
| 5.5   | .61  | 112                          | 4.0  | 1.59              | 6    | -18.1 | .124              | 54   | .54  | -78         |
| 6.0   | .64  | 102                          | 3.2  | 1.45              | -3   | -17.3 | .136              | 50   | .53  | <b>-</b> 85 |

A model for this device is available in the DEVICE MODELS section.

AT-41470 Noise Parameters:  $V_{CE} = 8 \text{ V}, I_{C} = 10 \text{ mA}$ 

| Freq. | NFo | Γ   | $R_{N}/50$ |                     |  |
|-------|-----|-----|------------|---------------------|--|
| GHz   | dB  | Mag | Ang        | 1t <sub>N</sub> /30 |  |
| 0.1   | 1.2 | .12 | 5          | 0.17                |  |
| 0.5   | 1.2 | .11 | 17         | 0.17                |  |
| 1.0   | 1.3 | .06 | 35         | 0.17                |  |
| 2.0   | 1.6 | .21 | 160        | 0.16                |  |
| 4.0   | 3.0 | .45 | -150       | 0.20                |  |

## 70 mil Package Dimensions



Package marking is "414"